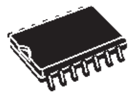
74LCX14

LOW VOLTAGE CMOS HEX SCHMITT INVERTER WITH 5V TOLERANT INPUTS

- 5V TOLERANT INPUTS
- HIGH SPEED:
  t_{PD} = 6.5 ns (MAX.) at V_{CC} = 3.0V
- POWER-DOWN PROTECTION ON INPUTS AND OUTPUTS
- SYMMETRICAL OUTPUT IMPEDANCE:
  $|I_{OH}| = I_{OL}$ = 24 mA (MIN)
- PCI BUS LEVELS GUARANTEED AT 24mA
- BALANCED PROPAGATION DELAYS:
  $t_{PLH} \cong t_{PHL}$
- OPERATING VOLTAGE RANGE:
  V_{CC} (OPR) = 2.0V to 3.6V (1.5V Data Retention)
- PIN AND FUNCTION COMPATIBLE WITH 74 SERIES 14
- LATCH-UP PERFORMANCE EXCEEDS 500mA
- ESD PERFORMANCE:
  HBM >2000V; MM > 200V


M
(Micro Package)


T
(TSSOP Package)

ORDER CODES :
74LCX14M 74LCX14T

DESCRIPTION

The LCX14 is a low voltage CMOS HEX SCHMITT INVERTER fabricated with sub-micron silicon gate and double-layer metal wiring C^2MOS technology. It is ideal for low power and high speed 3.3V applications; it can be interfaced to 5V signal enviroment for inputs.

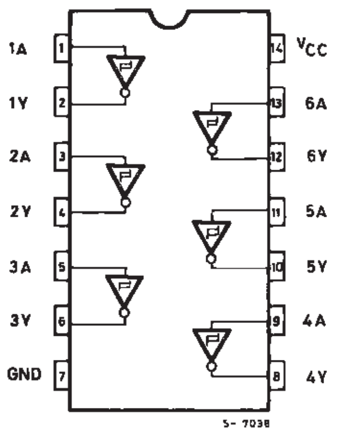
It has same speed performance at 3.3V than 5V, AC/ACT family, combined with a lower power consumption.

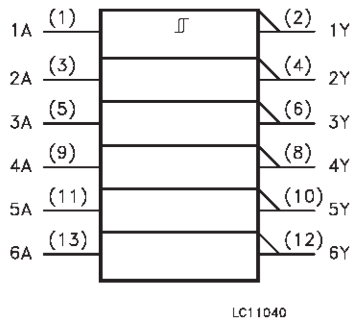
Pin configuration and function are the same as those of the LCX04 but the LCX14 has hysteresis between the positive and negative input threshold typically of 0.8V.

This together with its schmitt trigger function allows it to be used on line receivers with slow rise/fall input signals.

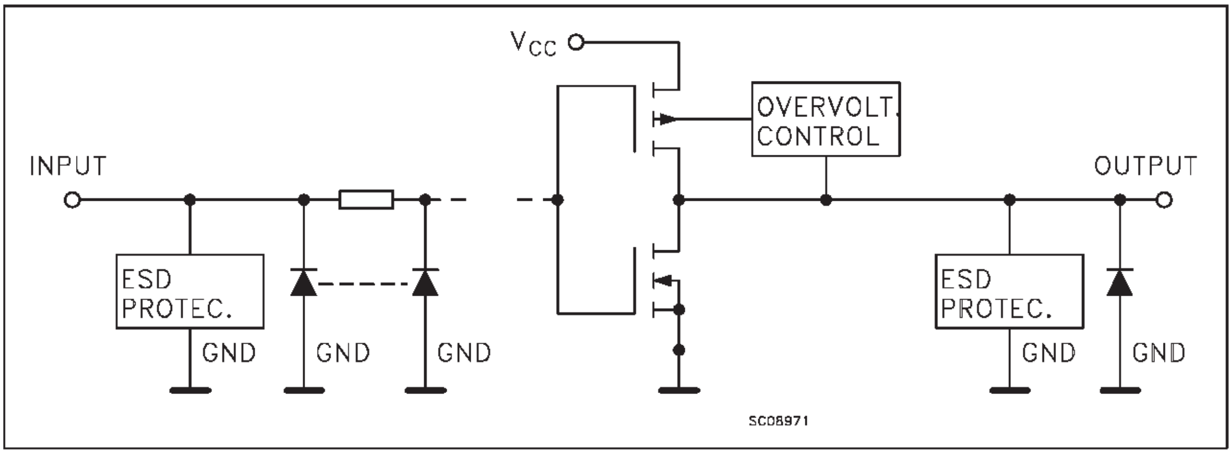
All inputs and outputs are equipped with protection circuits against static discharge, giving them 2KV ESD immunity and transient excess voltage.

PIN CONNECTION AND IEC LOGIC SYMBOLS





INPUT AND OUTPUT EQUIVALENT CIRCUIT



PIN DESCRIPTION

PIN No	SYMBOL	NAME AND FUNCTION
1, 3, 5, 9, 11, 13	1A to 6A	Data Inputs
2, 4, 6, 8, 10, 12	1Y to 6Y	Data Outputs
7	GND	Ground (0V)
14	V_{CC}	Positive Supply Voltage

TRUTH TABLE

A	Y
L	H
H	L

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	-0.5 to + 7.0	V
V_I	DC Input Voltage	-0.5 to + 7.0	V
V_O	DC Output Voltage (V_{CC}=0V)	-0.5 to + 7.0	V
V_O	DC Output Voltage (High or Low State) (note1)	-0.5 to V_{CC} + 0.5	V
I_{IK}	DC Input Diode Current	- 50	mA
I_{OK}	DC Output Diode Current (note2)	± 50	mA
I_O	DC Output Source/Sink Current	± 50	mA
I_{CC}	DC Supply Current per Supply Pin	± 100	mA
I_{GND}	DC Ground Current per Supply Pin	± 100	mA
T_{stg}	Storage Temperature	-65 to +150	°C
T_L	Lead Temperature (10 sec)	300	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.
1) I_O absolute maximum rating must be observed
2) V_O < GND, V_O > V_{CC}

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage (note 1)	2.0 to 3.6	V
V_I	Input Voltage	0 to 5.5	V
V_O	Output Voltage (V_{CC} = 0V)	0 to 5.5	V
V_O	Output Voltage (High or Low State)	0 to V_{CC}	V
I_{OH}, I_{OL}	High or Low Level Output Current (V_{CC} = 3.0 to 3.6V)	± 24	mA
I_{OH}, I_{OL}	High or Low Level Output Current (V_{CC} = 2.7 to 3.0V)	± 12	mA
T_{op}	Operating Temperature:	-40 to +85	^oC

1) Truth Table guaranteed: 1.5V to 3.6V

DC SPECIFICATIONS

Symbol	Parameter	Test Conditions			Value		Unit
		V_{CC} (V)			-40 to 85 ^oC		
					Min.	Max.	
V_{t+}	Positive Input Threshold	3.0			1.2	2.2	V
V_{t-}	Negative Input Threshold	3.0			0.6	1.5	V
V_H	Hysterisis Voltage	3.0			0.4	1.2	V
V_{OH}	High Level Output Voltage	2.7 to 3.6	V_I = V_{IL}	I_O=-100 µA	V_{CC}-0.2		V
		2.7		I_O=-12 mA	2.2		
		3.0		I_O=-18 mA	2.4		
				I_O=-24 mA	2.2		
V_{OL}	Low Level Output Voltage	2.7 to 3.6	V_I = V_{IH}	I_O=100 µA		0.2	V
		2.7		I_O=12 mA		0.4	
		3.0		I_O=16 mA		0.4	
		3.0		I_O=24 mA		0.55	
I_I	Input Leakage Current	2.7 to 3.6	V_I = 0 to 5.5 V			±5	µA
I_{off}	Power Off Leakage Current	0	V_I or V_O = 5.5V			100	µA
I_{CC}	Quiescent Supply Current	2.7 to 3.6	V_I = V_{CC} or GND			10	µA
			V_I or V_O = 3.6 to 5.5V			±10	
ΔI_{CC}	ICC incr. per input	2.7 to 3.6	V_{IH} = V_{CC} -0.6V			500	µA

DYNAMIC SWITCHING CHARACTERISTICS

Symbol	Parameter	Test Conditions		Value			Unit
		V_{CC} (V)		T_A = 25 ^oC			
				Min.	Typ.	Max.	
V_{OLP}	Dynamic Low Voltage Quiet Output (note 1)	3.3	C_L = 50 pF V_{IL} = 0 V V_{IH} = 3.3V		0.8		V
V_{OLV}					-0.8		

1) Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH to LOW or LOW t o HIGH. The remaining output is measured in the LOW state.

AC ELECTRICAL CHARACTERISTICS (C_L = 50 pF, R_L = 500 Ω, Input t_r = t_f = 2.5 ns)

Symbol	Parameter	Test Condition		Value		Unit
		V_{CC} (V)	Waveform	-40 to 85 °C		
				Min.	Max.	
t_{PLH} t_{PHL}	Propagation Delay Time	2.7	1		6.0	ns
		3.0 to 3.6		1.5	6.5	
t_{OSLH} t_{OSHL}	Output to Output Skew Time (note 1, 2)	3.0 to 3.6			1.0	ns

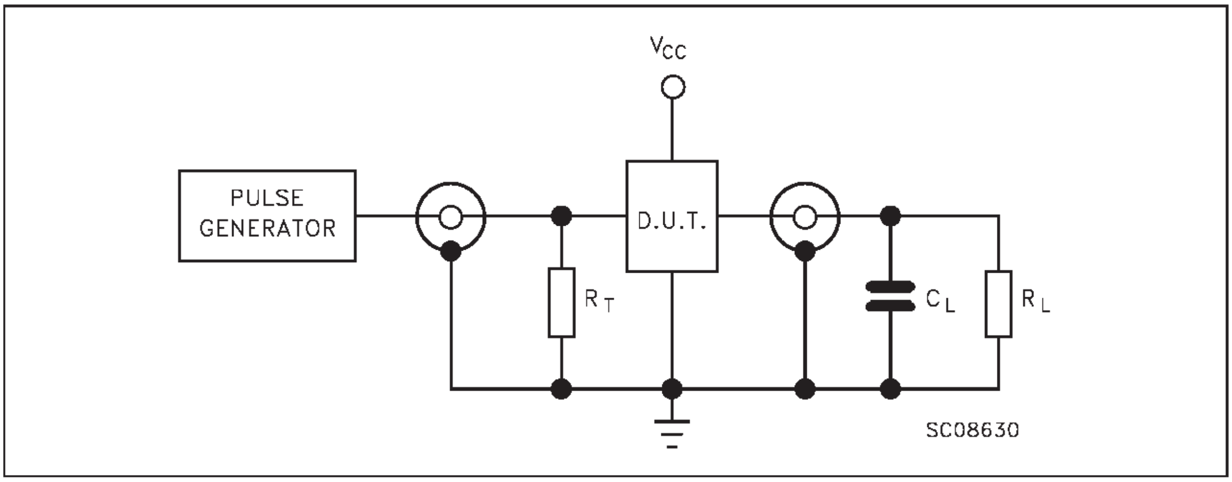
1) Skew is defined as the absolute value of the difference between the actual propagation delay for any two outputs of the same device switching in the same direction, either HIGH or LOW (t_{OSLH} = $|t_{PLHm} - t_{PLHn}|$, t_{OSHL} = $|t_{PHLm} - t_{pHLn}|$)
2) Parameter guaranteed by design

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Test Conditions		Value			Unit
		V_{CC} (V)		T_A = 25 °C			
				Min.	Typ.	Max.	
C_{IN}	Input Capacitance	3.3	V_{IN} = 0 to V_{CC}		6		pF
C_{PD}	Power Dissipation Capacitance (note 1)	3.3	f_{IN} = 10MHz V_{IN} = 0 or V_{CC}		48		pF

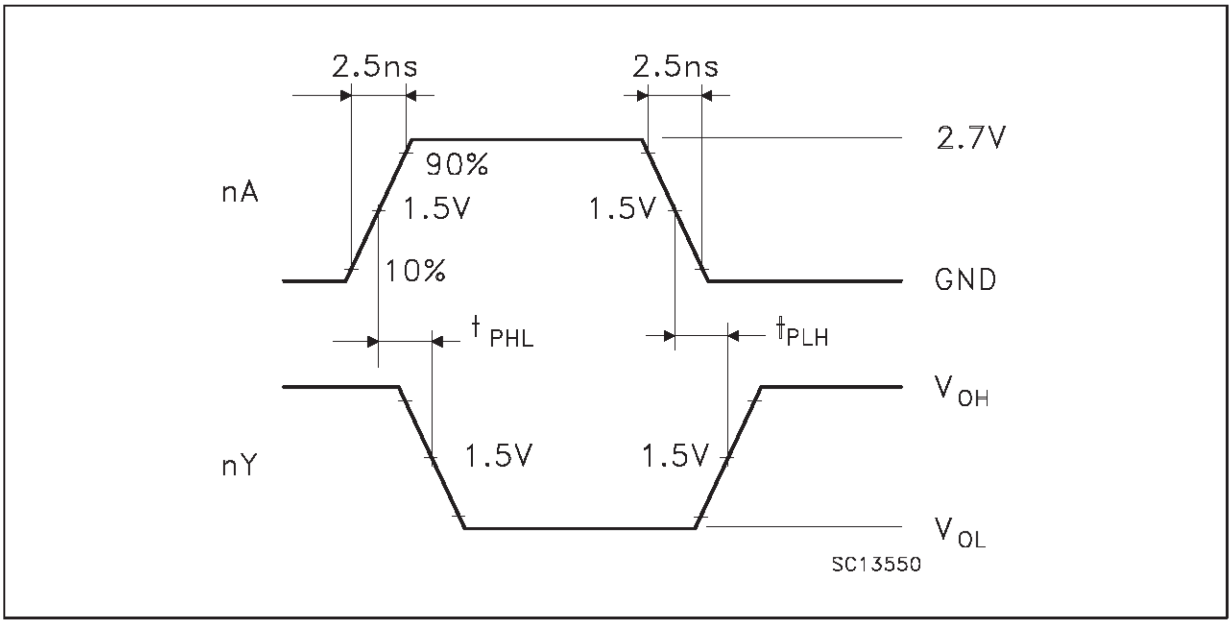
1) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. Average operting current can be obtained by the following equation. $I_{CC}(opr) = C_{PD} \bullet V_{CC} \bullet f_{IN} + I_{CC}/6$ (per gate)

TEST CIRCUIT



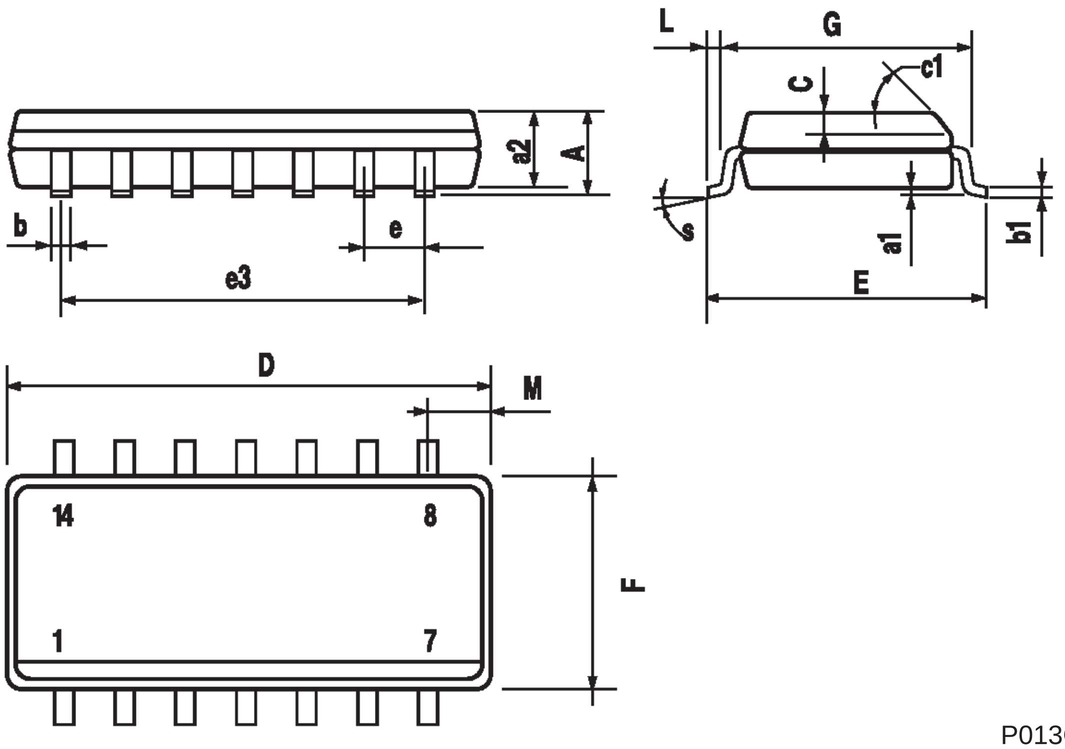
C_L = 50 pF or equivalent (includes jig and probe capacitance)
R_L = 500Ω or equivalent
R_T = Z_{OUT} of pulse generator (typically 50Ω)

WAVEFORM: PROPAGATION DELAYS (f=1MHz; 50% duty cycle)



SO-14 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			1.75			0.068
a1	0.1		0.2	0.003		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.019	
c1	45 (typ.)					
D	8.55		8.75	0.336		0.344
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		7.62			0.300	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.68			0.026
S	8 (max.)					



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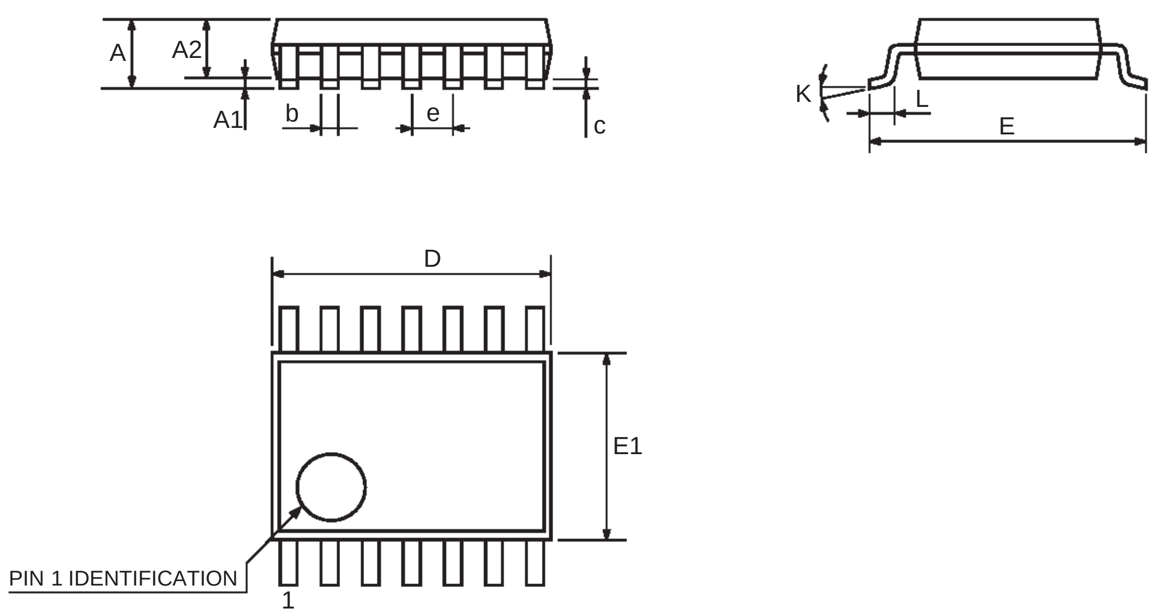
TSSOP14 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			1.1			0.433
A1	0.05	0.10	0.15	0.002	0.004	0.006
A2	0.85	0.9	0.95	0.335	0.354	0.374
b	0.19		0.30	0.0075		0.0118
c	0.09		0.20	0.0035		0.0079
D	4.9	5	5.1	0.193	0.197	0.201
E	6.25	6.4	6.5	0.246	0.252	0.256
E1	4.3	4.4	4.48	0.169	0.173	0.176
e		0.65 BSC			0.0256 BSC	
K	0^o	4^o	8^o	0^o	4^o	8^o
L	0.50	0.60	0.70	0.020	0.024	0.028



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